



# RLT808-150GS

## TECHNICAL DATA



### High Power Infrared Laser Diode

#### Features

- Lasing Mode Structure: single mode
- Peak Wavelength : typ. 808 nm
- Optical Output Power: 150 mW
- Package: 9 mm



#### Electrical Connection

Pin Configuration		Bottom View								
<p><b>n-type</b></p> <table border="1"> <thead> <tr> <th>PIN</th> <th>Function</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>LD Anode</td> </tr> <tr> <td>2</td> <td>LD Cathode, PD Cathode</td> </tr> <tr> <td>3</td> <td>PD Anode</td> </tr> </tbody> </table>	PIN	Function	1	LD Anode	2	LD Cathode, PD Cathode	3	PD Anode		
PIN	Function									
1	LD Anode									
2	LD Cathode, PD Cathode									
3	PD Anode									

#### Absolute Maximum Ratings ( $T_c=25^\circ\text{C}$ )

Item	Symbol	Value	Unit
Kink Free Power	$P_K$	160	mW
Operating Case Temperature	$T_c$	-20 ... +50	°C
Storage Temperature	$T_{stg}$	-40 ... +80	°C

#### Specifications ( $T_c=25^\circ\text{C}$ )

Item	Symbol	Min.	Typ.	Max.	Unit
<b>Optical Specification</b>					
CW Output Power	$P_O$	-	150	-	mW
Peak Wavelength	$\lambda_P$	803	808	813	nm
Spectral Width (FWHM)	$\Delta\lambda$	-	0.5	2	nm
FWHM Beam Divergence	$\theta_{  }$	-	8	11	deg
	$\theta_{\perp}$	13	17	22	deg
Emitting Aperature	$W \times H$		5 x 1		μm
Lifetime		100000	-	-	hour
<b>Electrical Specification</b>					
Threshold Current	$I_{th}$	-	30	50	mA
Operating Current	$I_{op}$	-	180	220	mA
Slope Efficiency	$\eta$	0.9	1.0	-	W/A
Operating Voltage	$V_{op}$	-	1.9	2.2	V
Monitor Current	$I_m$				mA

The above specifications are for reference purpose only and subjected to change without prior notice.





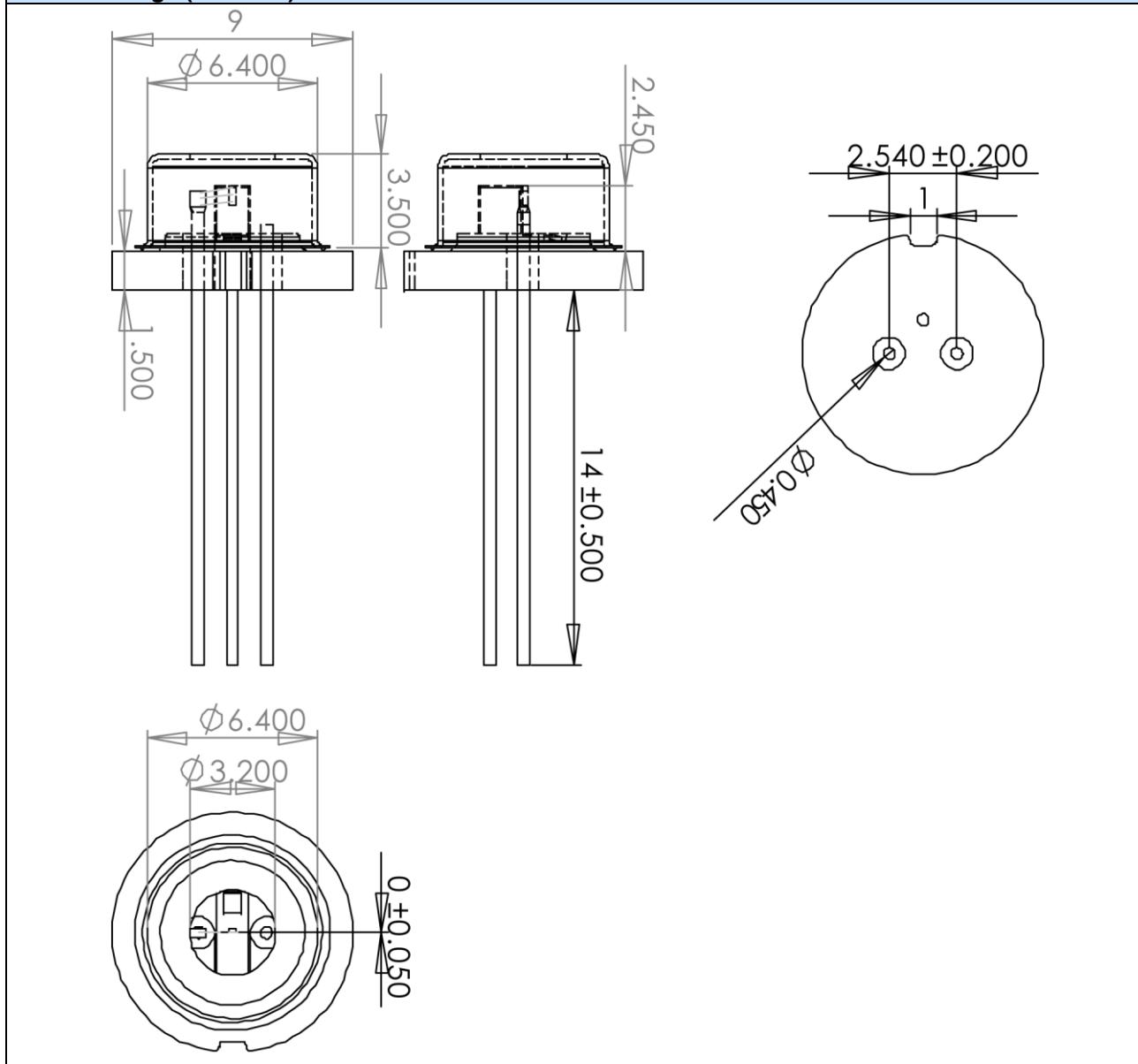
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### Package Dimensions

#### 9 mm Package (Unit:mm)





**ROITHNER LASERTECHNIK** GmbH

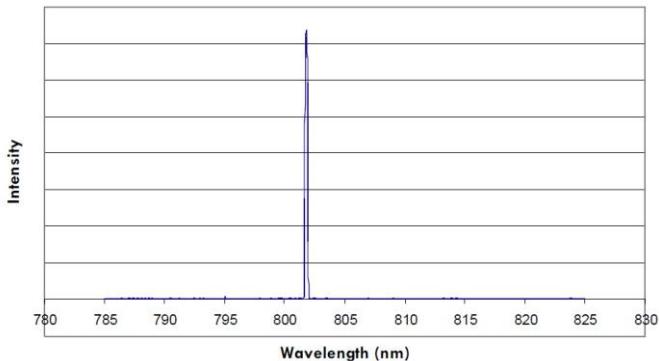
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## Typical Performance Curves

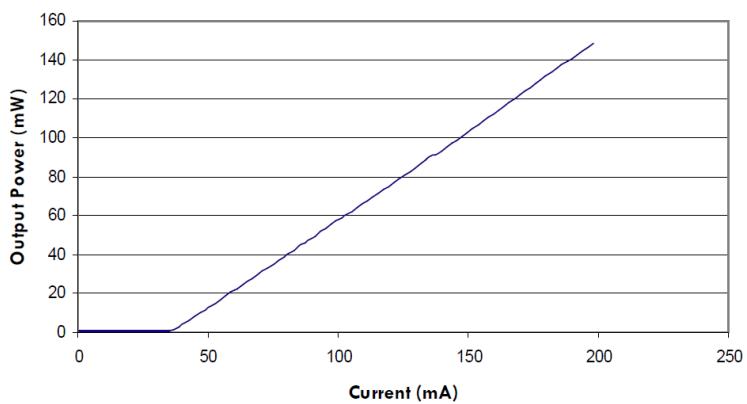
### Spectrum

808nm 150mW Spectrum



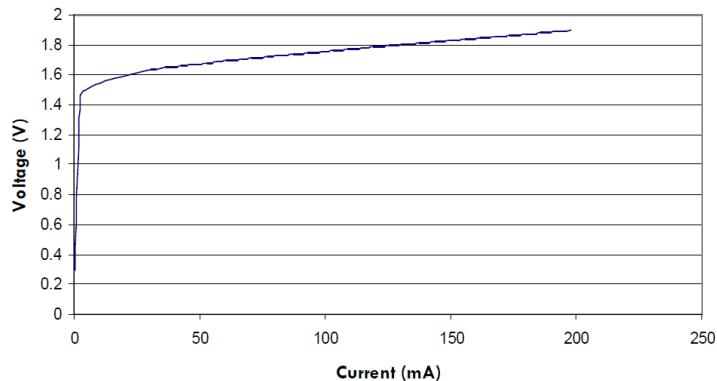
### Operation Current vs. Output Power

808nm 150mW LI



### Operation Current vs. Operation Voltage

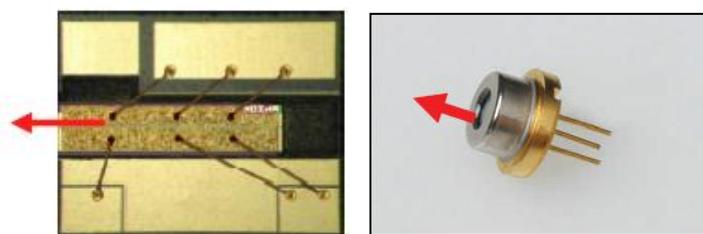
808nm 150mW VI





## Safety of Laser light

- Laser Light can damage the human eyes and skin. Do not expose the eye or skin directly to any laser light and/or through optical lens. When handling the LDs, wear appropriate safety glasses to prevent laser light, even any reflections from entering to the eye. Focused laser beam through optical instruments will increase the chance of eye hazard.
- **WARNING: Laser diode is emitting invisible light**



## Cautions

### 1. Operating method

- This LD shall change its forward voltage requirement and optical output power according to temperature change. Also, the LD will require more operation current to maintain same output power as it degrades.
- Confirm that electrical spike current generated by switching on and off does not exceed the maximum operating current level specified herein above as absolute maximum rating. Also, employ appropriate countermeasures to reduce chattering and/or overshooting in the circuit.

### 2. Static Electricity

- Static electricity or electrical surges will reduce and degrade the reliability of the LDs. It is recommended to use a wrist trap or anti-electrostatic glove when handling the product.

### 3. Absolute Maximum Rating

- Active layer of LDs shall have high current density and generate high electric field during its operation. In order to prevent excessive damage, the LD must be operated strictly below absolute maximum rating.